





N-CHANNEL ENHANCEMENT MODE FIELD EFFECT TRANSISTOR

Features

- Low Gate Threshold Voltage
- Low Input Capacitance
- Fast Switching Speed
- Low Input/Output Leakage
- High Drain-Source Voltage Rating
- Lead Free/RoHS Compliant (Note 2)
- Qualified to AEC-Q101 Standards for High Reliability
- "Green" Device, Note 3 and 4

Mechanical Data

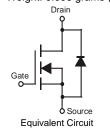
- Case: SOT-323
- Case Material: Molded Plastic, "Green" Molding Compound, Note 4. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020C
- Terminal Connections: See Diagram
- Terminals: Solderable per MIL-STD-202, Method 208
- Lead Free Plating (Matte Tin Finish annealed over Alloy 42 leadframe).
- Marking Information: See Page 3
- Ordering Information: See Page 3
- Weight: 0.006 grams (approximate)

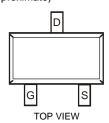
SOT-323



TOP VIEW







Maximum Ratings @TA = 25°C unless otherwise specified

Characte	eristic	Symbol	Value	Units	
Drain-Source Voltage		V_{DSS}	100	V	
Drain-Gate Voltage R _{GS} ≤ 20KΩ		V_{DGR}	100	V	
Gate-Source Voltage	Continuous	V _{GSS}	±20	V	
Drain Current (Note 1)	Continuous Pulsed	I _D I _{DM}	170 680	mA	

Thermal Characteristics @T_A = 25°C unless otherwise specified

Characteristic	Symbol	Value	Units	
Total Power Dissipation (Note 1)	P_d	200	mW	
Thermal Resistance, Junction to Ambient (Note 1)	$R_{ hetaJA}$	625	°C/W	
Operating and Storage Temperature Range	T_j , T_{STG}	-55 to +150	°C	

Notes:

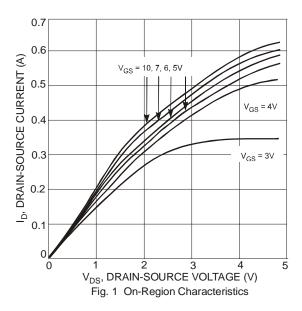
- 1. Part mounted on FR-4 board with recommended pad layout, which can be found on our website at http://www.diodes.com/datasheets/ap02001.pdf.
- No purposefully added lead.
- Diodes Inc.'s "Green" policy can be found on our website at http://www.diodes.com/products/lead_free/index.php.
- Product manufactured with Date Code 0627 (week 27, 2006) and newer are built with Green Molding Compound. Product manufactured prior to Date Code 0627 are built with Non-Green Molding Compound and may contain Halogens or Sb2O3 Fire Retardants.



Electrical Characteristics @T_A = 25°C unless otherwise specified

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 5)							
Drain-Source Breakdown Voltage	BV _{DSS}	100	_		V	$V_{GS} = 0V, I_D = 250\mu A$	
Zero Gate Voltage Drain Current		_		1.0	μΑ	$V_{DS} = 100V, V_{GS} = 0V$	
Zero Gate Voltage Drain Current	I _{DSS}			10	nA	$V_{DS} = 20V$, $V_{GS} = 0V$	
Gate-Body Leakage, Forward	I _{GSSF}	_	_	50	nA	$V_{GS} = 20V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 5)							
Gate Threshold Voltage	$V_{GS(th)}$	0.8	1.4	2.0	V	$V_{DS} = V_{GS}$, $I_D = 1mA$	
Static Drain-Source On-Resistance	R _{DS} (ON)	_	_	6.0	Ω	$V_{GS} = 10V, I_D = 0.17A$	
Static Drain-Source Ori-Resistance		_	_	10		$V_{GS} = 4.5V, I_D = 0.17A$	
Forward Transconductance	g FS	80	370		mS	$V_{DS} = 10V$, $I_D = 0.17A$, $f = 1.0KHz$	
Drain-Source Diode Forward Voltage	V_{SD}	_	0.84	1.3	V	$V_{GS} = 0V, I_{S} = 0.34A$	
DYNAMIC CHARACTERISTICS							
Input Capacitance	C _{iss}	_	29	60	рF		
Output Capacitance	Coss	_	10	15	рF	$V_{DS} = 25V, V_{GS} = 0V, f = 1.0MHz$	
Reverse Transfer Capacitance	C _{rss}	_	2	6	pF		
SWITCHING CHARACTERISTICS							
Turn-On Rise Time	t _r	_	_	8	ns		
Turn-Off Fall Time	t _f	_	_	16	ns	$V_{DD} = 30V, I_D = 0.28A,$	
Turn-On Delay Time	t _{D(ON)}	_	_	8	ns	$R_{GEN} = 50\Omega$, $V_{GS} = 10V$	
Turn-Off Delay Time	t _{D(OFF)}	_		13	ns		

5. Short duration pulse test used to minimize self-heating effect.



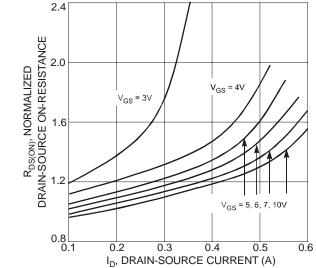


Fig. 2 On-Resistance Variation with Gate Voltage and Drain-Source Current



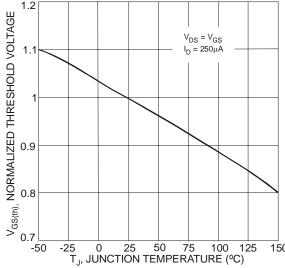
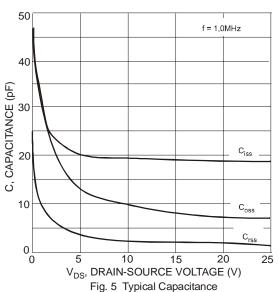


Fig. 3 Gate Threshold Variation with Temperature



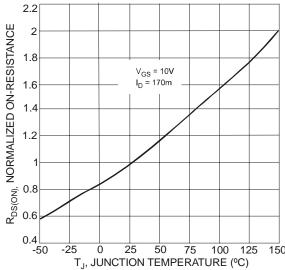
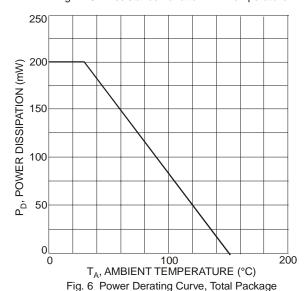


Fig. 4 On-Resistance Variation with Temperature

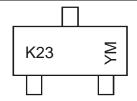


Ordering Information (Notes 4 & 6)

Part Number	Case	Packaging
BSS123W-7-F	SOT-323	3000/Tape & Reel

Notes: 6. For packaging details, go to our website at http://www.diodes.com/datasheets/ap02007.pdf.

Marking Information



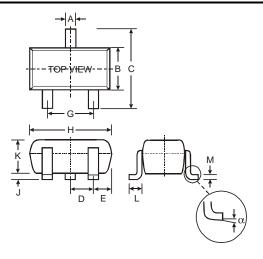
K23 = Product Type Marking Code YM = Date Code Marking Y = Year ex: N = 2002 M = Month ex: 9 = September

Date Code Key

Year	2002	2003	2004	2005	200)6 20	007	2008	2009	2010	2011	2012
Code	N	Р	R	S	Т		U	V	W	Χ	Υ	Z
Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	0	N	D

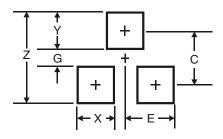


Package Outline Dimensions



SOT-323				
Dim	Min	Max		
Α	0.25	0.25		
В	1.15	1.35		
С	2.00	2.00		
D	0.65 Nominal			
Е	0.30	0.40		
G	1.20	1.40		
Н	1.80	2.20		
J	0.0	0.10		
K	0.90	1.00		
L	0.25	0.40		
M	0.10	0.18		
α	0°	8°		
All Dimensions in mm				

Suggested Pad Layout



Dimensions	Value (in mm)
Z	2.8
G	1.0
X	0.7
Υ	0.9
С	1.9
E	0.65

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